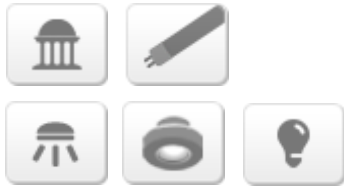


**Mid-Power LED – 3030 Series**
**S1W0-3030xx8003-00000000-0P006**
**STW8C2PB-NT**
**(Cool, Neutral, Warm)**


## Product Brief

### Description

- This White Colored surface-mount LED comes in standard package dimension. Package Size : 3.0x3.0x0.6mm
- It has a substrate made up of a molded plastic reflector sitting on top of a lead frame.
- The die is attached within the reflector cavity and the cavity is encapsulated by silicone.
- The package design coupled with careful selection of component materials allow these products to perform with high reliability.

### Features and Benefits

- Thermally Enhanced Package Design
- Mid Power to High Power up to 1.37W
- Max. Driving Current 400mA
- Compact Package Size
- High Color Quality with CRI Min.80
- Pb-free Reflow Soldering Application

### Key Applications

- Replacement lamps – Bulb, Tube
- Commercial
- Industrial
- Residential

**Table 1. Product Selection Table**

Product Code	Color	Nominal CCT	Part Number	CRI	
				Min	
STW8C2PB-NT-E1H1C1IZ	Cool White	6500K	S1W0-3030658003-00000000-0P006	80	
		5700K	S1W0-3030578003-00000000-0P006		
		5000K	S1W0-3030508003-00000000-0P006		
	Neutral White	4000K	S1W0-3030408003-00000000-0P006		
		3500K	S1W0-3030358003-00000000-0P006		
		Warm White	3000K		S1W0-3030308003-00000000-0P006
			2700K		S1W0-3030278003-00000000-0P006

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## Performance Characteristics

**Table 2. Product Selection Guide,  $I_f = 65\text{mA}$ ,  $T_j = 25^\circ\text{C}$ , RH30%**

CRI	CCT [K]	Luminous Flux <sup>[2]</sup> [lm] @65mA			Efficacy	PPF	PPE
					lm/W	$\mu\text{mol/s}$	$\mu\text{mol/J}$
		Min	Typ	Max	Typ	@65mA	@65mA
80	6500	33.9	36.2	37.5	206.3	0.50	2.85
	5700	33.9	37.0	37.5	210.8	0.51	2.91
	5000	35.1	37.8	39.0	215.4	0.51	2.92
	4000	35.1	37.7	39.0	214.8	0.51	2.89
	3500	33.9	36.2	37.5	206.3	0.49	2.79
	3000	33.0	35.7	37.5	203.4	0.49	2.79
	2700	33.0	35.2	37.5	200.6	0.48	2.75

**Notes :**

- (1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
- (2) Seoul Semiconductor maintains a tolerance of  $\pm 7\%$  on flux.

## Performance Characteristics

**Table 3. Characteristics,  $I_F=65\text{mA}$ ,  $T_j= 25^\circ\text{C}$ , RH30%**

Parameter	Symbol	Value			Unit
		Min	Typ	Max <sup>[4]</sup>	
Forward Current	$I_F$	-	65	-	mA
Forward Voltage <sup>[1]</sup>	$V_F$	2.6	2.7	2.8	V
CRI	$R_a$	80	81	-	
R9	$R_g$	0	4	-	
Viewing Angle <sup>[2]</sup>	$2\theta_{1/2}$	-	120	-	Deg.
Thermal resistance (J to S) <sup>[3]</sup>	$R\theta_{J-S}$	-	10	-	$^\circ\text{C/W}$
ESD Sensitivity(HBM)	-	Class 3A JEDEC JS-001-2017			

**Table 4. Absolute Maximum Ratings**

Parameter	Symbol	Value	Unit
Forward Current	$I_F$	400	mA
Power Dissipation	$P_D$	1.37	W
Junction Temperature	$T_j$	125	$^\circ\text{C}$
Operating Temperature	$T_{opr}$	-40 ~ + 85	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-40 ~ + 100	$^\circ\text{C}$

**Notes :**

[1] Tolerance :  $V_F : \pm 0.1\text{V}$ , Flux :  $\pm 7\%$ ,  $R_a : \pm 2$ ,  $x, y : \pm 0.005$

[2]  $2\theta_{1/2}$  is the off-axis where the luminous intensity is 1/2 of the peak intensity.

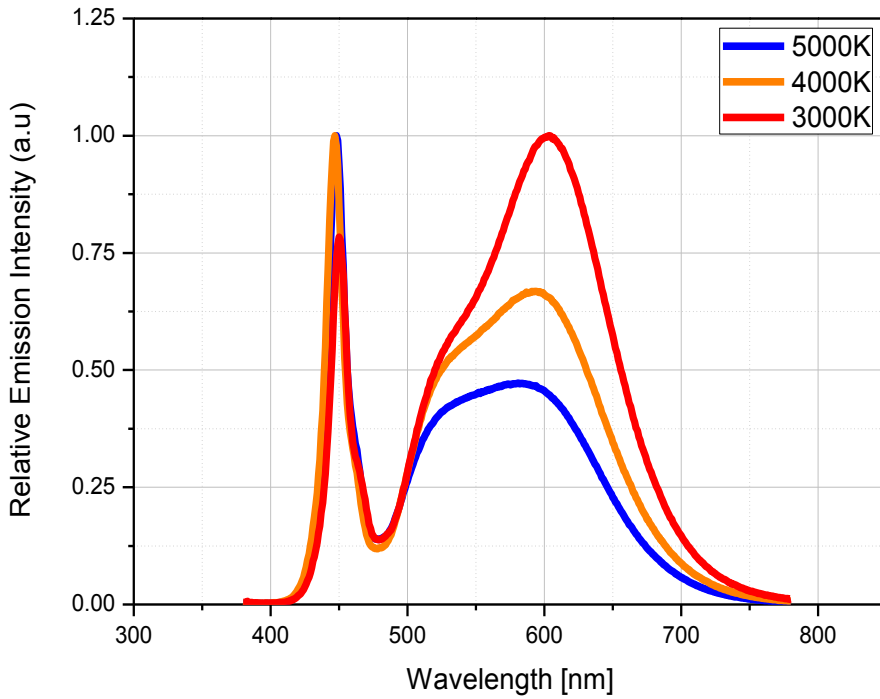
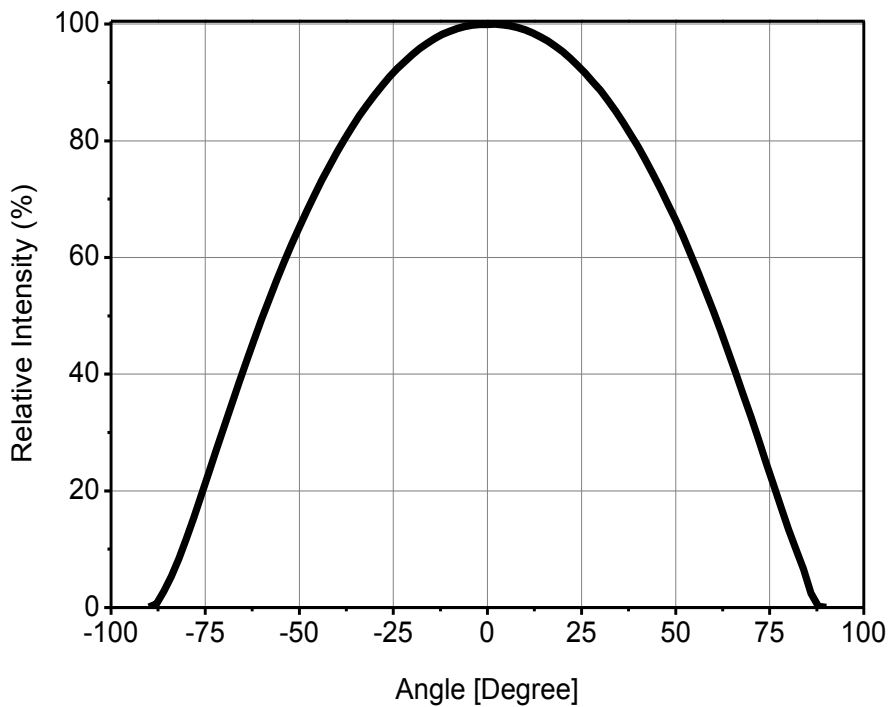
[3] Thermal resistance :  $R_{th_{J-S}}$  (Junction / solder)

[4] It is recommended to use it in the condition that the reliability is secured within the Max value.

- Calculated performance values are for reference only.

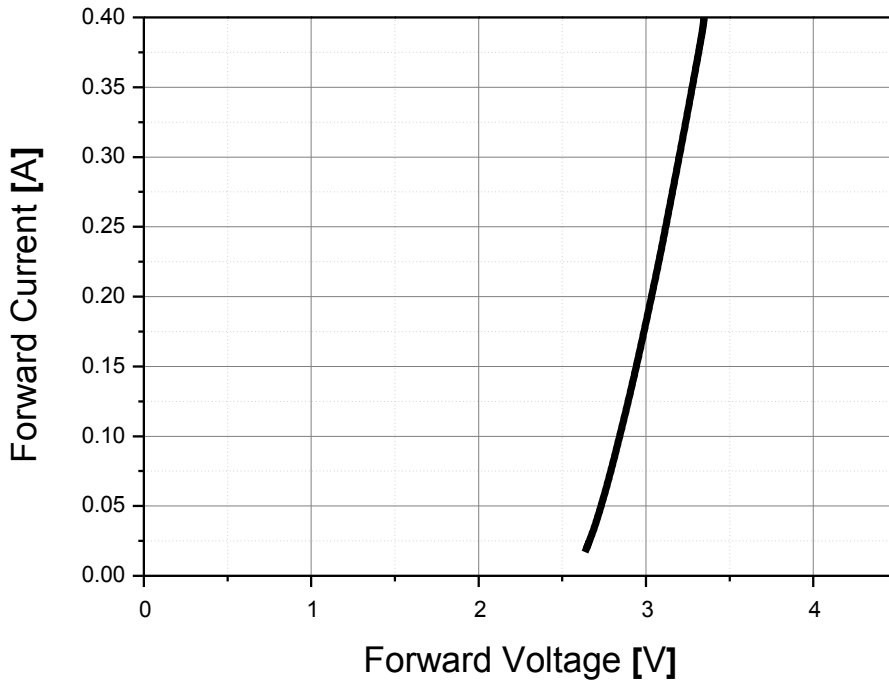
- LED's properties might be different from suggested values like above and below tables if operation condition will be exceeded our parameter range. Care is to be taken that power dissipation does not exceed the absolute maximum rating of the product.
- Thermal resistance can be increased substantially depending on the heat sink design/operating condition, and the maximum possible driving current will decrease accordingly.
- All measurements were made under the standardized environment of Seoul Semiconductor.

## Characteristics Graph

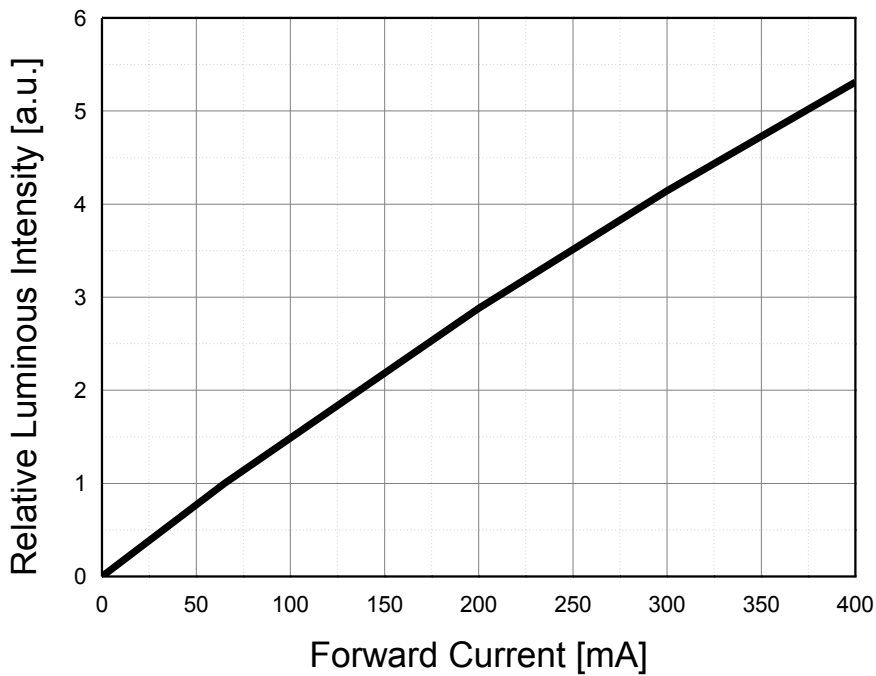
**Fig 1. Color Spectrum,  $T_j = 25^\circ\text{C}$** **Fig 2. Radiant Pattern,  $T_j = 25^\circ\text{C}$** 

## Characteristics Graph

**Fig 3. Forward Voltage vs. Forward Current,  $T_j = 25^\circ\text{C}$**



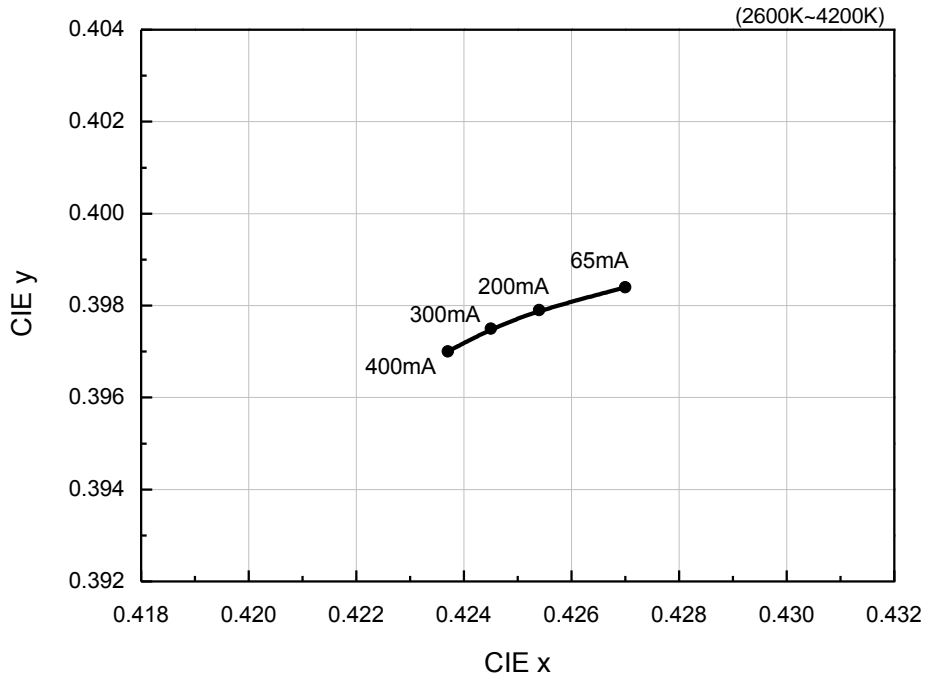
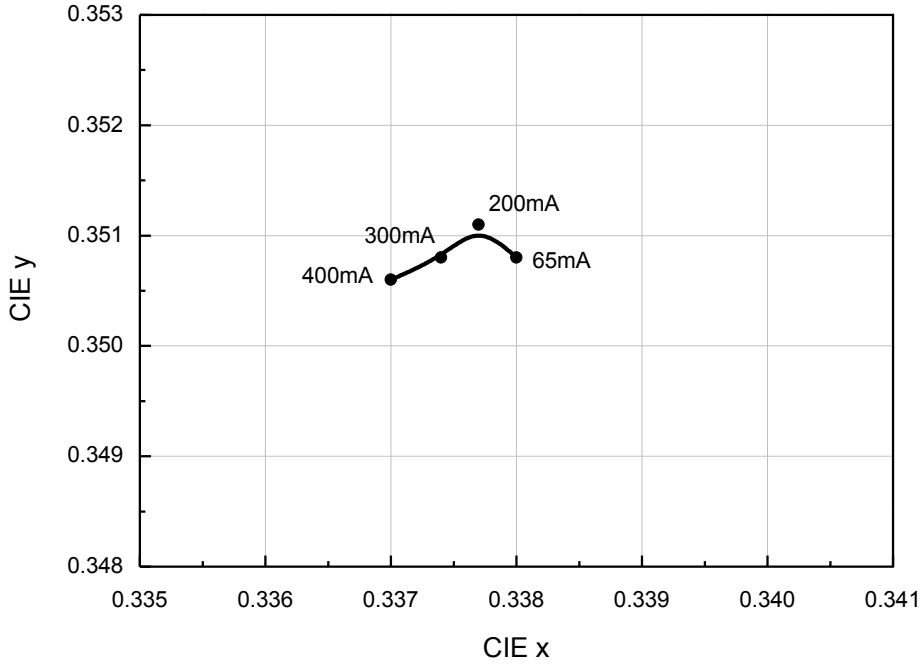
**Fig 4. Forward Current vs. Relative Luminous Flux,  $T_j = 25^\circ\text{C}$**



## Characteristics Graph

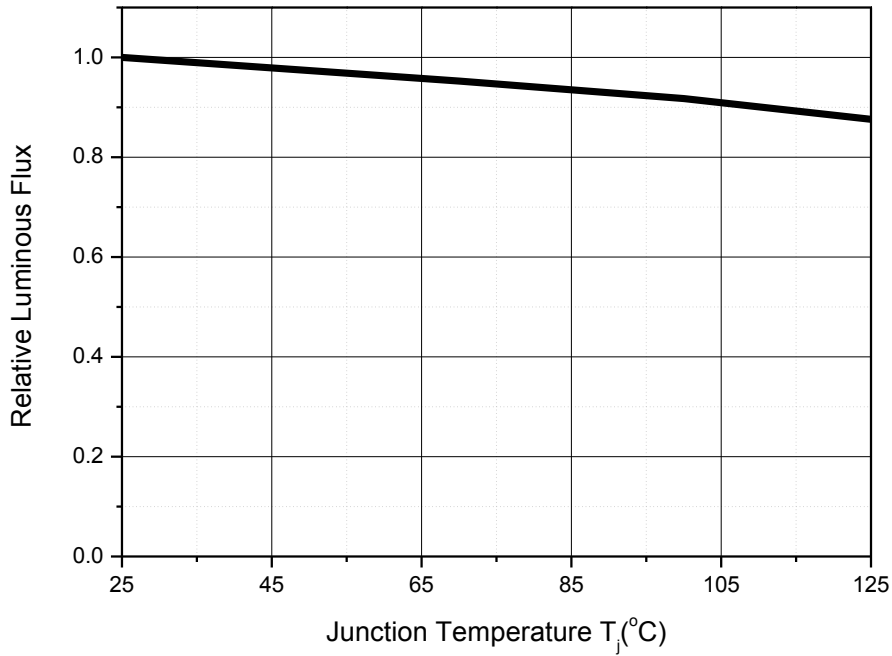
**Fig 5. Forward Current vs. CIE x, y Shift,  $T_j = 25^\circ\text{C}$** 

(4200K~7000K)

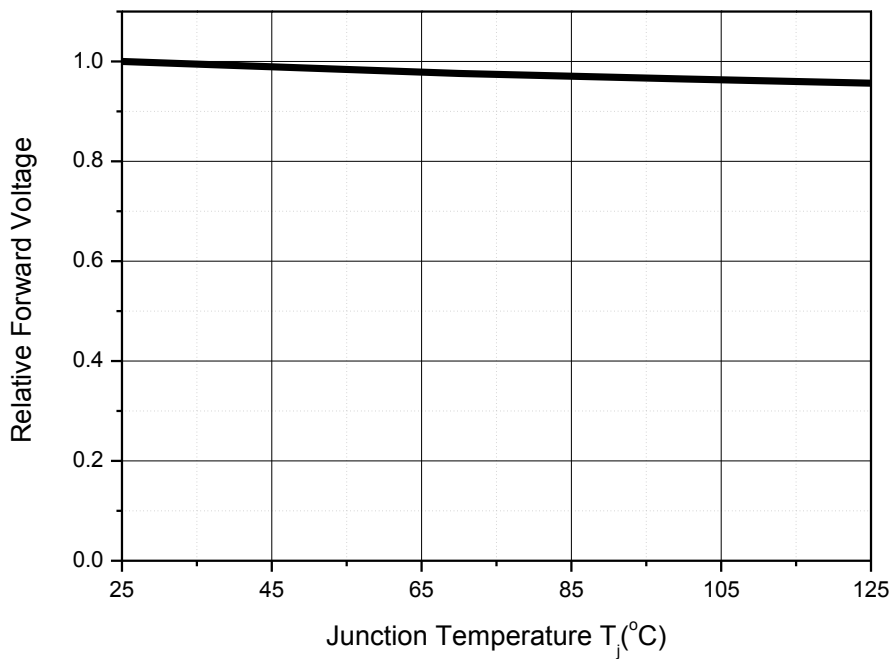


## Characteristics Graph

**Fig 6. Junction Temperature vs. Relative Luminous Flux,  $I_F=65\text{mA}$**

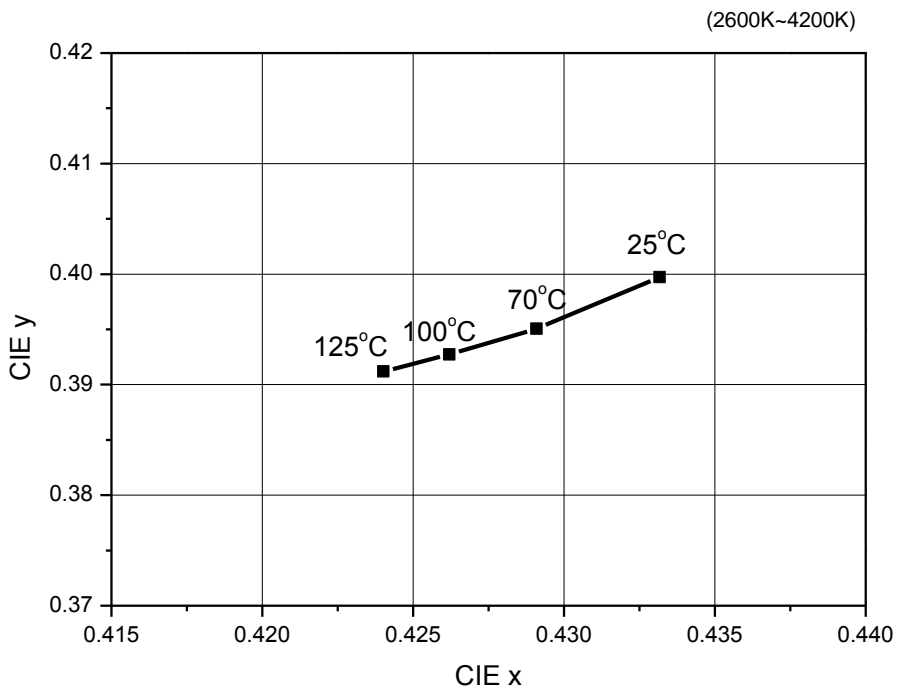
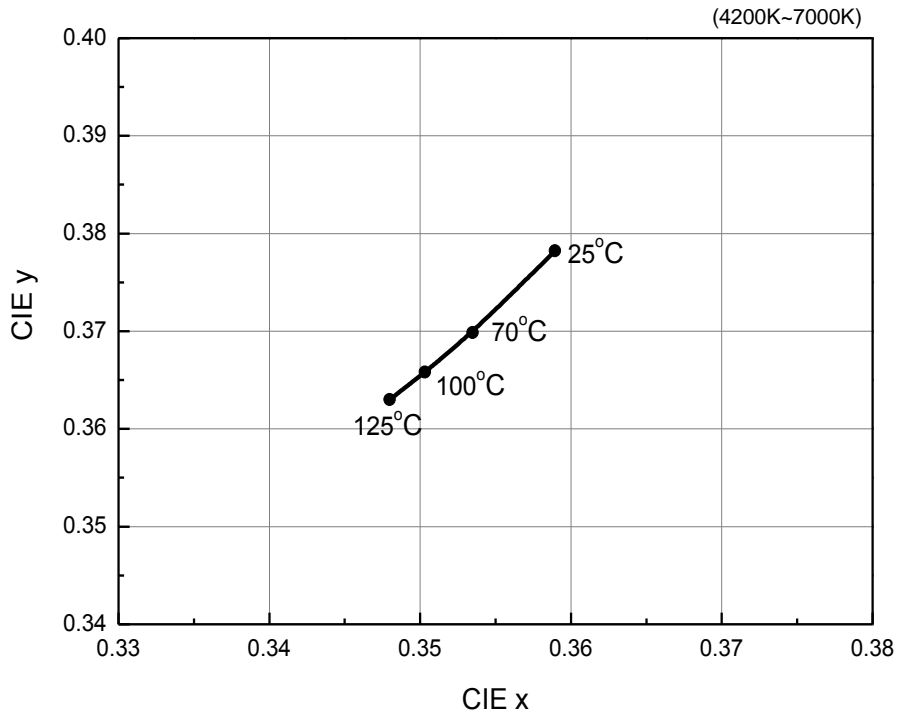


**Fig 7. Junction Temperature vs. Relative Forward Voltage,  $I_F=65\text{mA}$**



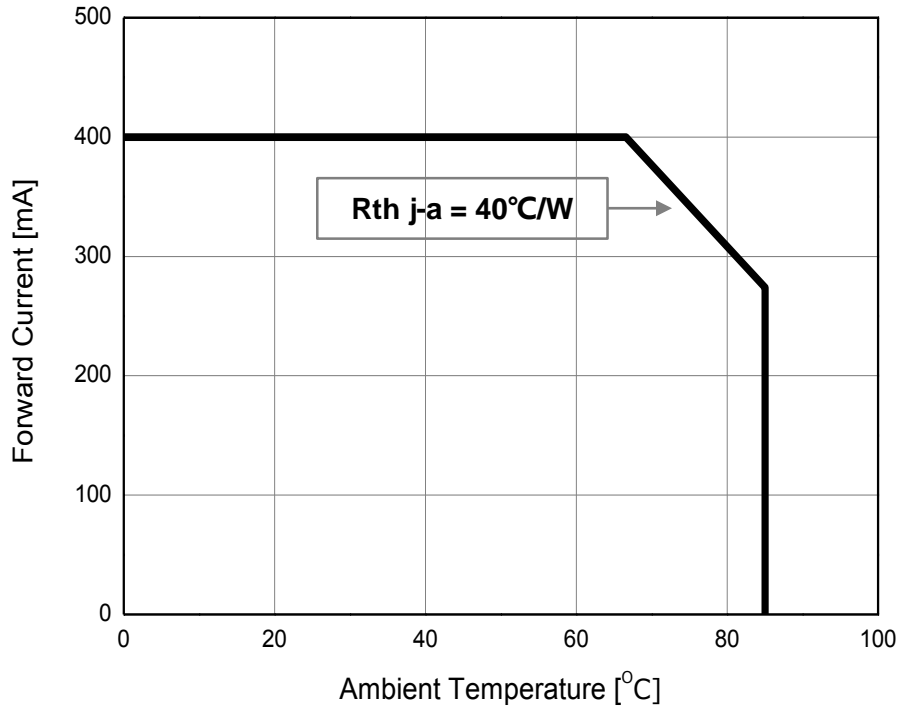


## Characteristics Graph

**Fig 8. Chromaticity Coordinate vs. Junction Temperature,  $I_F=65\text{mA}$** 


## Characteristics Graph

Fig 9. Ambient Temperature vs. Maximum Forward Current,  $T_{j,max} = 125^{\circ}\text{C}$



## Color Bin Structure

**Table 5. Bin Code description,  $T_j=25^{\circ}\text{C}$ ,  $I_f=65\text{mA}$** 

Part Number	Luminous Flux (lm)			Color Chromaticity Coordinate	Forward Voltage (V)		
	Bin Code	Min	Max		Bin Code	Min	Max
S1W0-3030xx 8003-0000000 0-0P006	U0	33.0	33.9	Refer to page.12	Y0	2.6	2.7
	U3	33.9	35.1				
	U7	35.1	37.5				
	V5	37.5	39.0		Y1	2.7	2.8

**Table 6. Flux rank distribution**
 Available ranks

CCT	CIE	Flux Rank			
6000 ~ 7000K	A	U0	U3	U7	V5
5300 ~ 6000K	B	U0	U3	U7	V5
4700 ~ 5300K	C	U0	U3	U7	V5
3700 ~ 4200K	E	U0	U3	U7	V5
3200 ~ 3700K	F	U0	U3	U7	V5
2900 ~ 3200K	G	U0	U3	U7	V5
2600 ~ 2900K	H	U0	U3	U7	V5

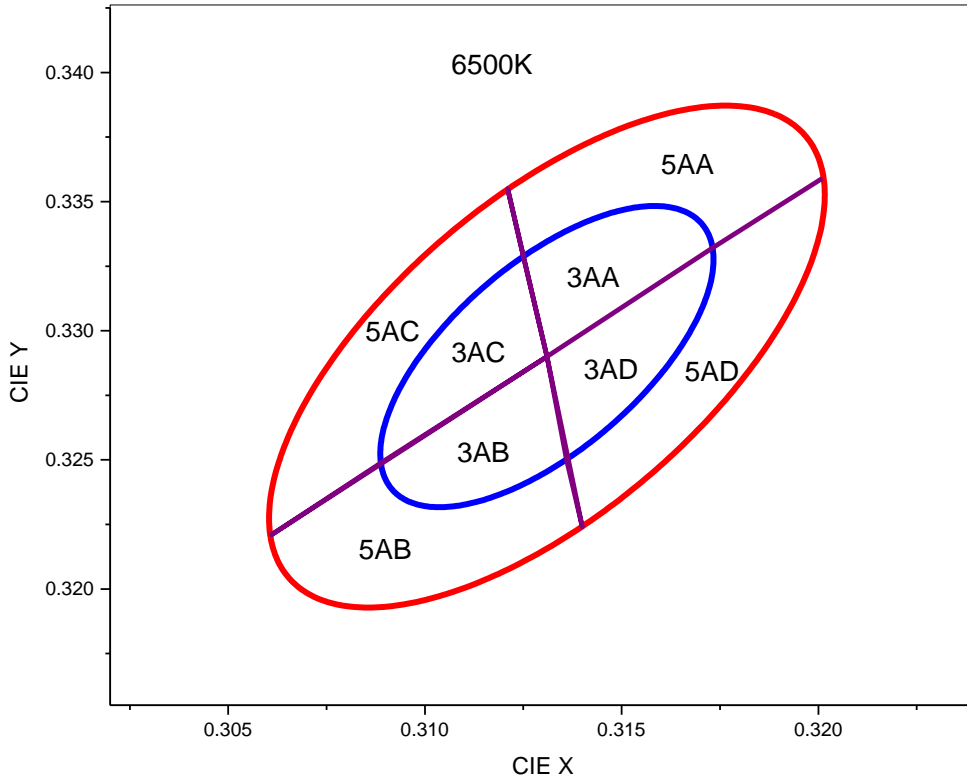
Notes :

All measurements were made under the standardized environment of Seoul Semiconductor.

In order to ensure availability, single color rank will not be orderable.

## Color Bin Structure

**CIE Chromaticity Diagram (Cool white),  $T_j=25^\circ\text{C}$ ,  $I_f=65\text{mA}$**



3A (3step)	
Center point	0.3131 : 0.3290
Major Axis a	0.00662
Major Axis b	0.00285
Ellipse Rotation Angle	58.38

5Step	
Center point	0.3131 : 0.3290
Major Axis a	0.01103
Major Axis b	0.00476
Ellipse Rotation Angle	58.38

CIE X

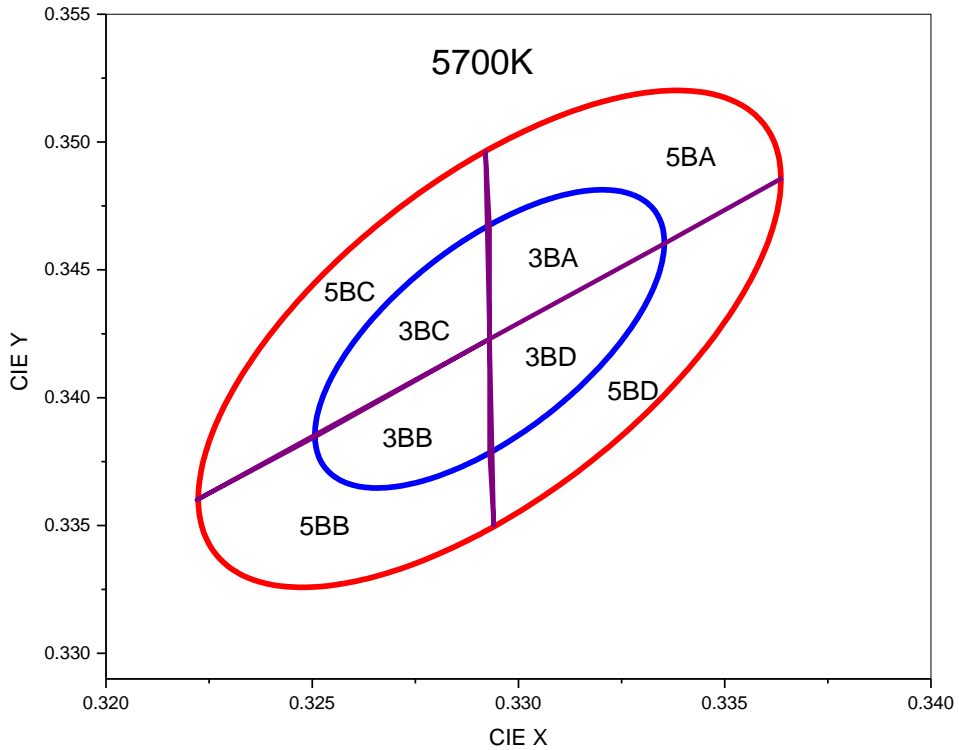
5AA,3AA		5AC,3AC	
CIE X	CIE Y	CIE X	CIE Y
0.3131	0.3290	0.3131	0.3290
0.3201	0.3359	0.3121	0.3355
0.3121	0.3355	0.3061	0.3221

5AB,3AB		5AD,3AD	
CIE X	CIE Y	CIE X	CIE Y
0.3131	0.3290	0.3131	0.3290
0.3061	0.3221	0.3140	0.3224
0.3140	0.3224	0.3201	0.3359

Kitting
5AA:5AB=5AC:5AD=1:1
3AA:3AB=3AC:3AD=1:1

## Color Bin Structure

CIE Chromaticity Diagram (Cool white),  $T_j=25^\circ\text{C}$ ,  $I_f=65\text{mA}$



3B (3step)	
Center point	0.3293 : 0.3423
Major Axis a	0.00662
Major Axis b	0.00285
Ellipse Rotation Angle	58.38

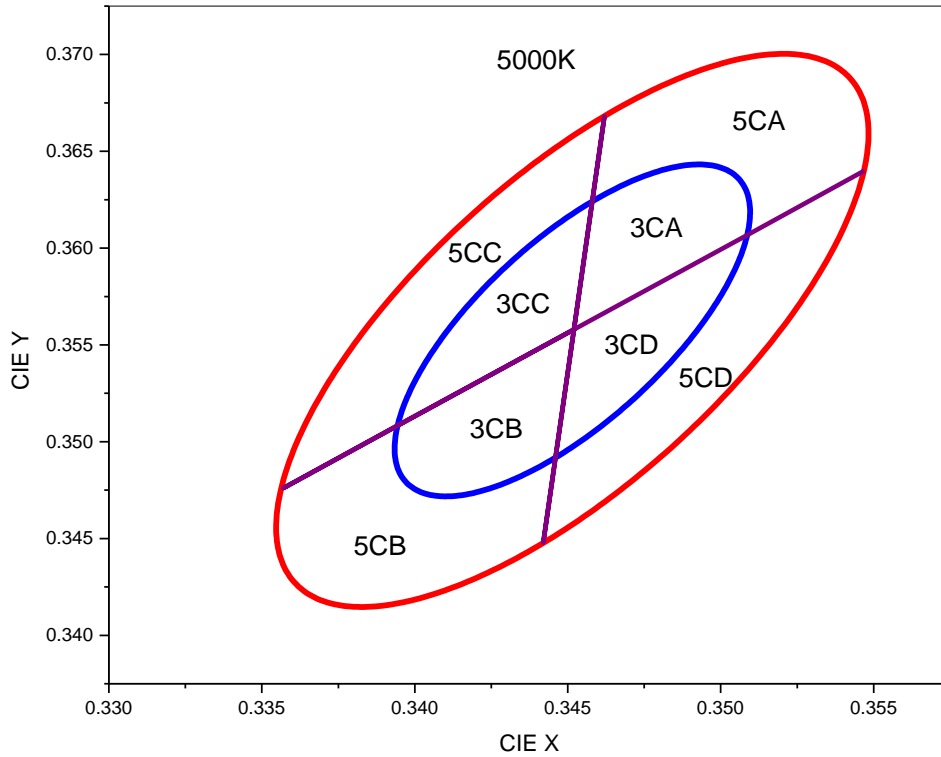
5Step	
Center point	0.3293 : 0.3423
Major Axis a	0.01103
Major Axis b	0.00476
Ellipse Rotation Angle	58.38

5BA,3BA		5BC,5BC	
CIE X	CIE Y	CIE X	CIE Y
0.3293	0.3423	0.3293	0.3423
0.3364	0.3486	0.3292	0.3496
0.3292	0.3496	0.3222	0.3360
5BB,3BB		5BD,3BD	
CIE X	CIE Y	CIE X	CIE Y
0.3293	0.3423	0.3293	0.3423
0.3222	0.3360	0.3294	0.3350
0.3294	0.3350	0.3364	0.3486

Kitting	
5BA:5BB=5BC:5BD=1:1	
3BA:3BB=3BC:3BD=1:1	

## Color Bin Structure

**CIE Chromaticity Diagram (Cool white),  $T_j=25^\circ\text{C}$ ,  $I_f=65\text{mA}$**



3C (3step)	
Center point	0.3452 : 0.3558
Major Axis a	0.00971
Major Axis b	0.0036
Ellipse Rotation Angle	59.62

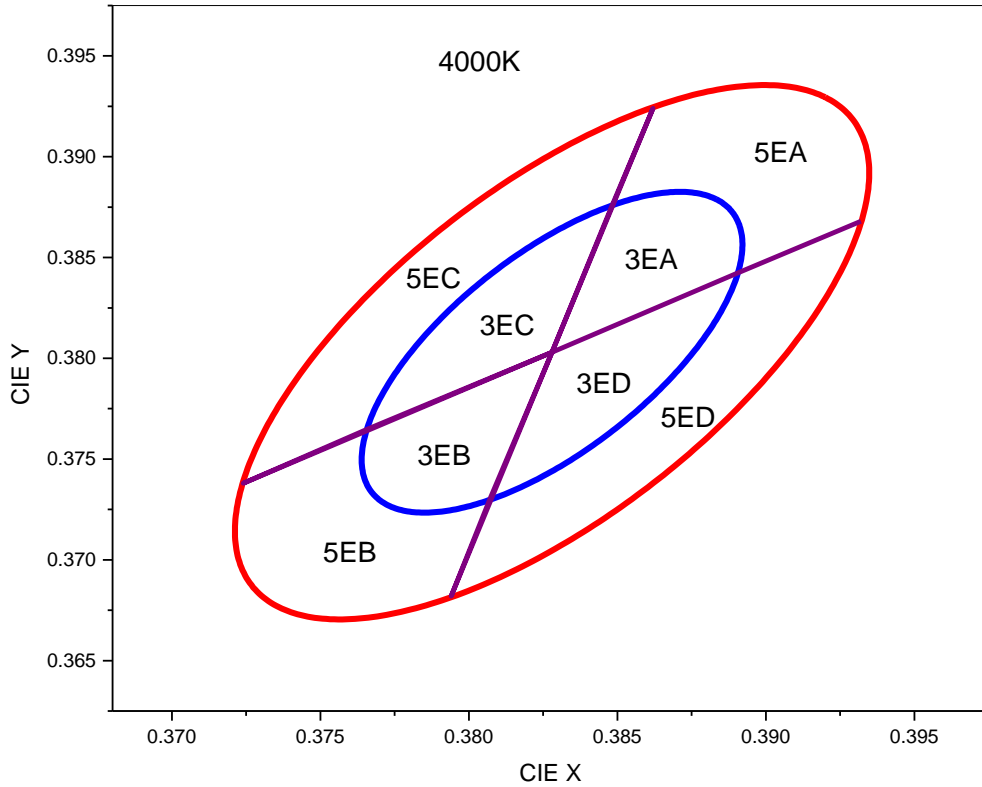
5Step	
Center point	0.3452 : 0.3558
Major Axis a	0.01618
Major Axis b	0.006
Ellipse Rotation Angle	59.62

5CA,3CA		5CC,3CC	
CIE X	CIE Y	CIE X	CIE Y
0.3452	0.3558	0.3452	0.3558
0.3547	0.3640	0.3462	0.3668
0.3462	0.3668	0.3357	0.3476
5CB,3CB		5CD,3CD	
CIE X	CIE Y	CIE X	CIE Y
0.3452	0.3558	0.3452	0.3558
0.3357	0.3476	0.3442	0.3448
0.3442	0.3448	0.3547	0.3640

Kitting	
5CA:5CB=5CC:5CD=1:1	
3CA:3CB=3CC:3CD=1:1	

## Color Bin Structure

CIE Chromaticity Diagram (Neutral white),  $T_j=25^{\circ}\text{C}$ ,  $I_f=65\text{mA}$



3E (3step)	
Center point	0.3828 : 0.3803
Major Axis a	0.00939
Major Axis b	0.00403
Ellipse Rotation Angle	54.00

5Step	
Center point	0.3828 : 0.3803
Major Axis a	0.01564
Major Axis b	0.00672
Ellipse Rotation Angle	54.00

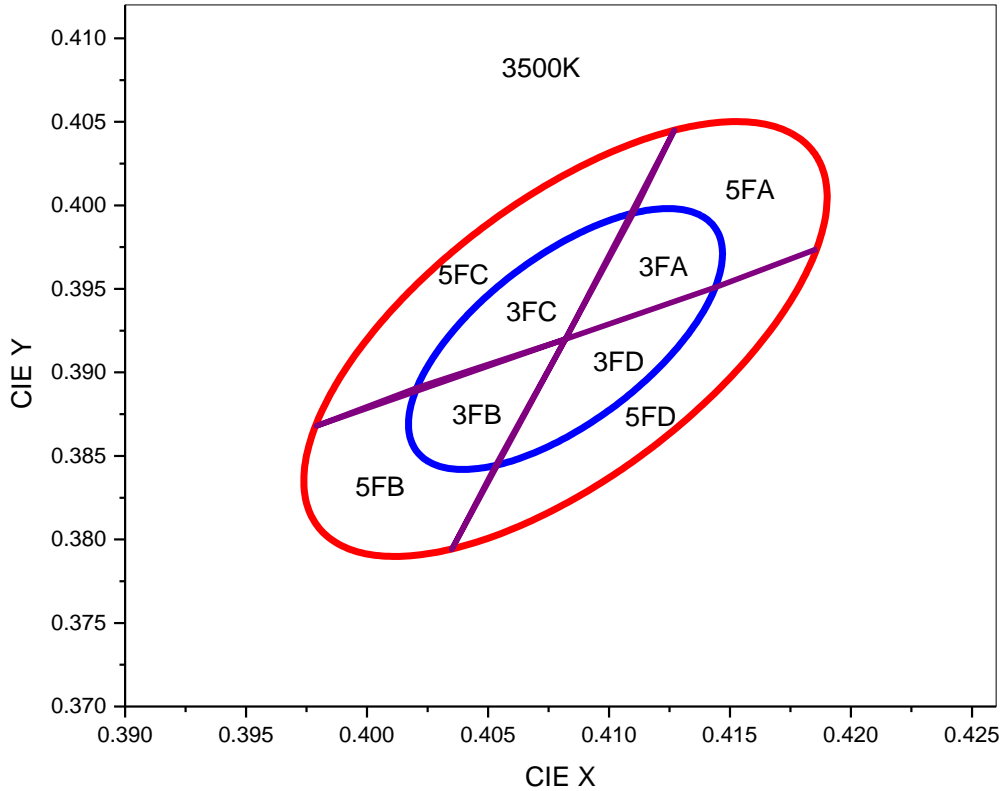
5EA,3EA		5EC,3EC	
CIE X	CIE Y	CIE X	CIE Y
0.3828	0.3803	0.3828	0.3803
0.3932	0.3868	0.3862	0.3924
0.3862	0.3924	0.3724	0.3738

5EB,3EB		5ED,3ED	
CIE X	CIE Y	CIE X	CIE Y
0.3828	0.3803	0.3828	0.3803
0.3724	0.3738	0.3794	0.3682
0.3794	0.3682	0.3932	0.3868

Kitting	
5EA:5EB=5EC:5ED=1:1	
3EA:3EB=3EC:3ED=1:1	

## Color Bin Structure

**CIE Chromaticity Diagram (Warm white),  $T_j=25^\circ\text{C}$ ,  $I_f=65\text{mA}$** 


3F (3step)	
Center point	0.4082 : 0.3920
Major Axis a	0.00927
Major Axis b	0.00414
Ellipse Rotation Angle	52.96

5Step	
Center point	0.4082 : 0.3920
Major Axis a	0.01545
Major Axis b	0.0069
Ellipse Rotation Angle	52.96

5FA,3FA		5FC,3FC	
CIE X	CIE Y	CIE X	CIE Y
0.4082	0.3920	0.4082	0.3920
0.3989	0.3797	0.4027	0.3962
0.4027	0.3962	0.4175	0.4043

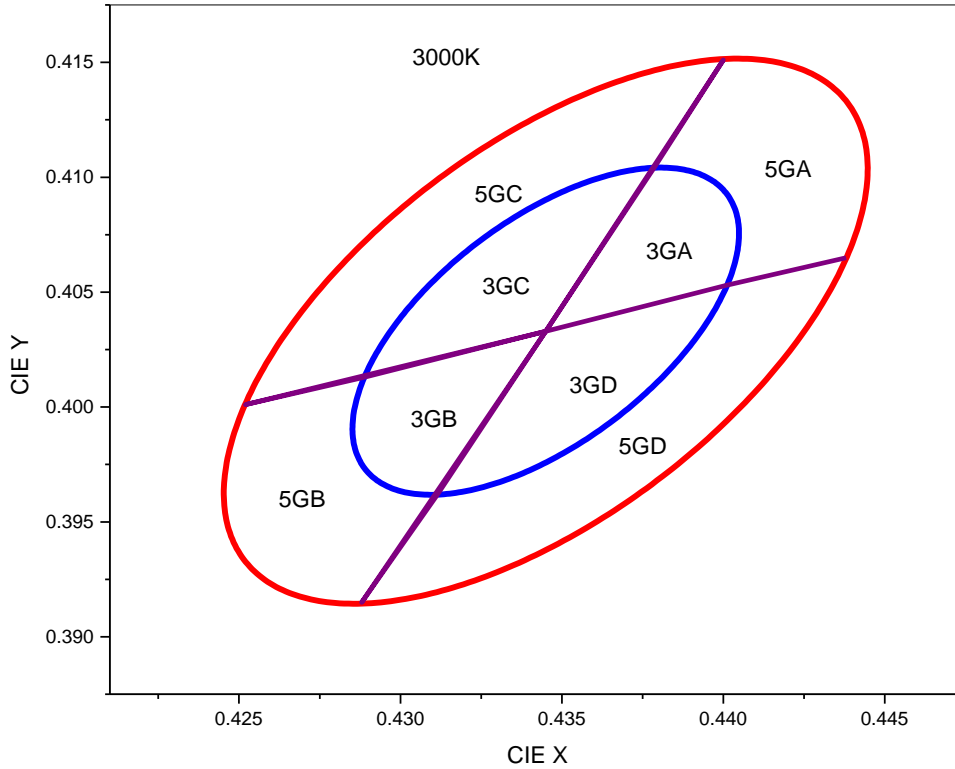
5FB,3FB		5FD,3FD	
CIE X	CIE Y	CIE X	CIE Y
0.4082	0.3920	0.4082	0.3920
0.4175	0.4043	0.4137	0.3878
0.4137	0.3878	0.3989	0.3797

Kitting	
5FA:5FB=5FC:5FD=1:1	
3FA:3FB=3FC:3FD=1:1	



## Color Bin Structure

**CIE Chromaticity Diagram (Warm white),  $T_j=25^\circ\text{C}$ ,  $I_f=65\text{mA}$**



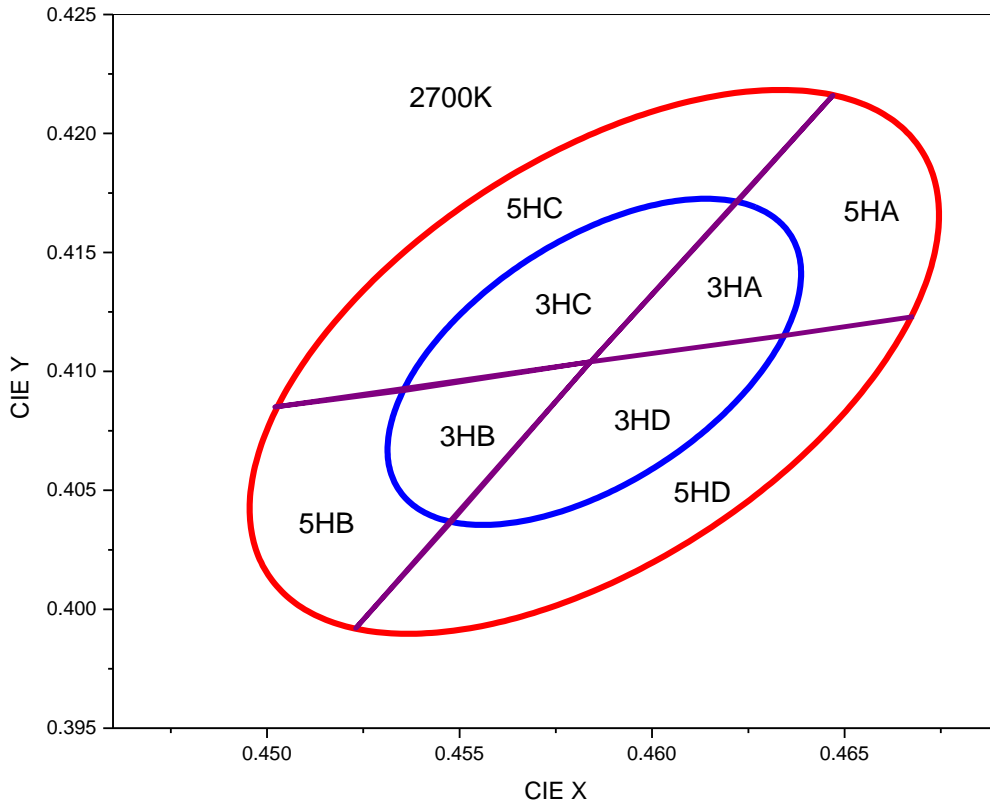
3G (3step)	
Center point	0.4345 : 0.4033
Major Axis a	0.00835
Major Axis b	0.0041
Ellipse Rotation Angle	53.16

5Step	
Center point	0.4345 : 0.4033
Major Axis a	0.01391
Major Axis b	0.00683
Ellipse Rotation Angle	53.16

5GA,3GA		5GC,3GC	
CIE X	CIE Y	CIE X	CIE Y
0.4345	0.4033	0.4345	0.4033
0.4262	0.3922	0.4290	0.4074
0.4290	0.4074	0.4428	0.4144
5GB,3GB		5GD,3GD	
CIE X	CIE Y	CIE X	CIE Y
0.4345	0.4033	0.4345	0.4033
0.4428	0.4144	0.4262	0.3922
0.4400	0.3992	0.4400	0.3992

Kitting
5GA:5GB=5GC:5GD=1:1
3GA:3GB=3GC:3GD=1:1

## Color Bin Structure

**CIE Chromaticity Diagram (Warm white),  $T_j=25^\circ\text{C}$ ,  $I_f=65\text{mA}$** 


3H (3step)	
Center point	0.4585 : 0.4104
Major Axis a	0.00773
Major Axis b	0.00401
Ellipse Rotation Angle	57.28

5Step	
Center point	0.4585 : 0.4104
Major Axis a	0.01289
Major Axis b	0.00668
Ellipse Rotation Angle	57.28

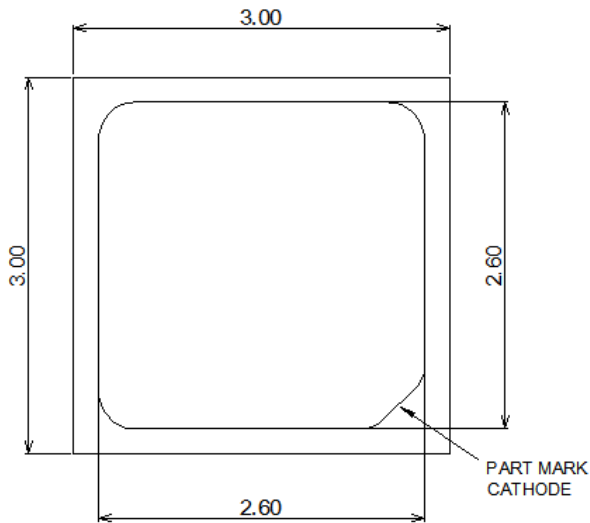
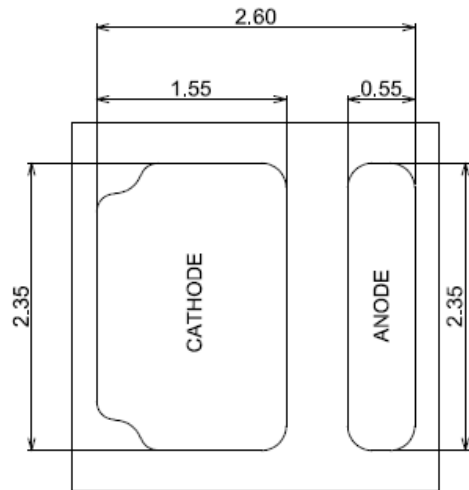
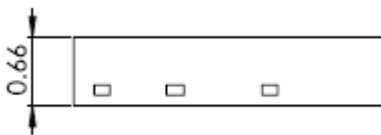
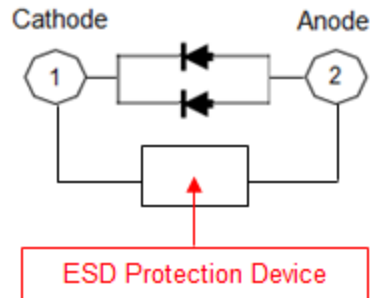
5HA,3HA		5HC,3HC	
CIE X	CIE Y	CIE X	CIE Y
0.4585	0.4104	0.4585	0.4104
0.4668	0.4123	0.4647	0.4216
0.4647	0.4216	0.4502	0.4085

5HB,3HB		5HD,3HD	
CIE X	CIE Y	CIE X	CIE Y
0.4585	0.4104	0.4585	0.4104
0.4502	0.4085	0.4523	0.3992
0.4523	0.3992	0.4668	0.4123

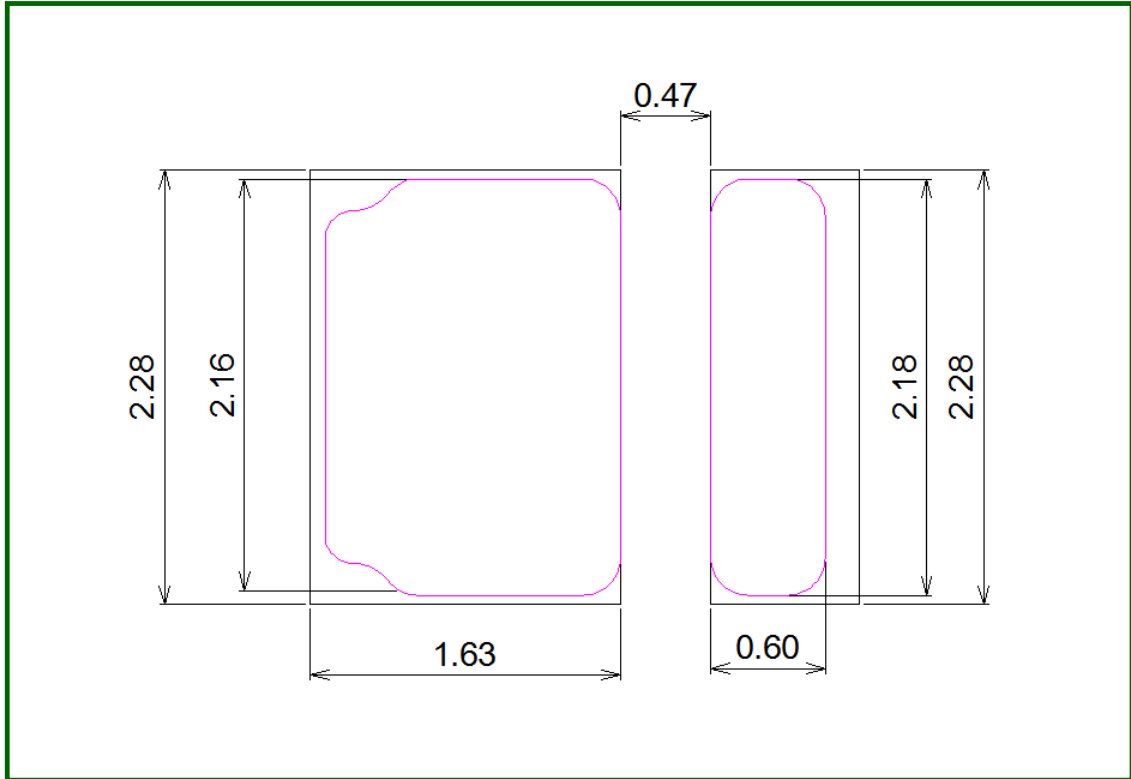
Kitting
5HA:5HB=5HC:5HD=1:1
3HA:3HB=3HC:3HD=1:1

## Mechanical Dimensions

**Top View**

**Bottom View**

**Side View**

**Circuit**


- (1) All dimensions are in millimeters.
- (2) Scale : none
- (3) Undefined tolerance is  $\pm 0.2\text{mm}$

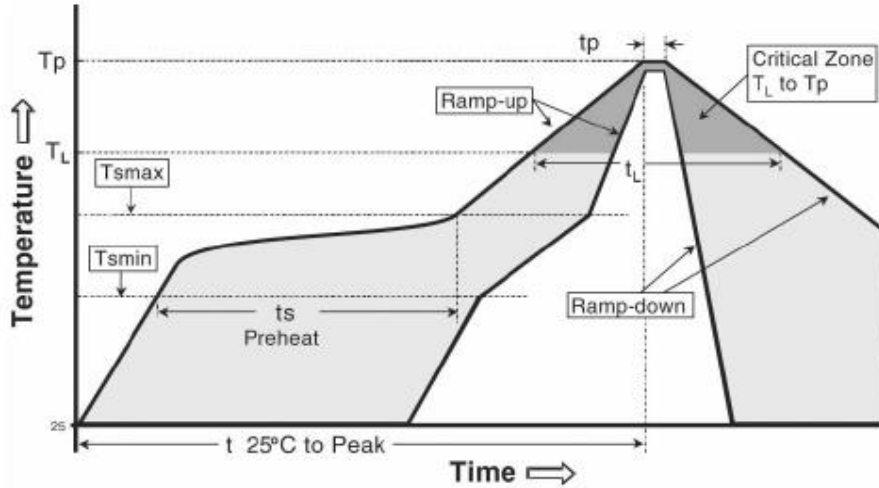
## Recommended Solder Pad



### Notes :

- (1) All dimensions are in millimeters.
- (2) Scale : none
- (3) This drawing without tolerances are for reference only
- (4) Undefined tolerance is  $\pm 0.1\text{mm}$

## Reflow Soldering Characteristics

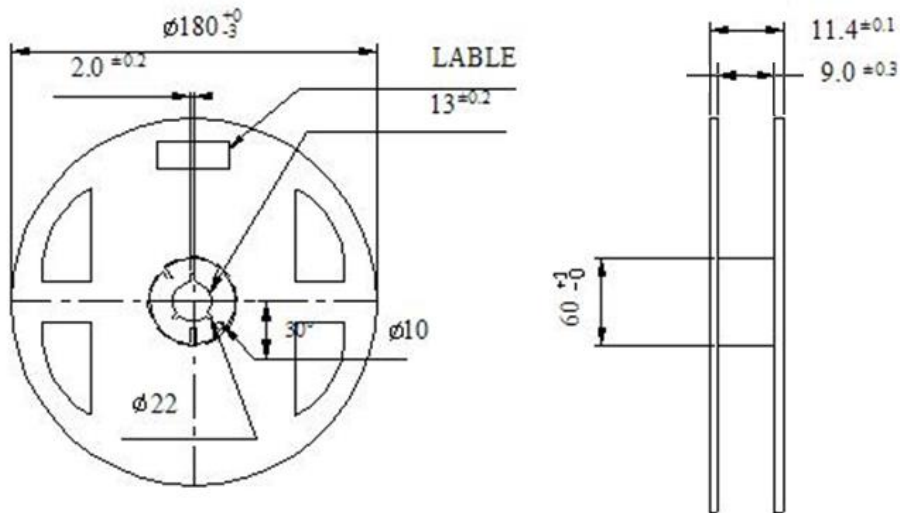
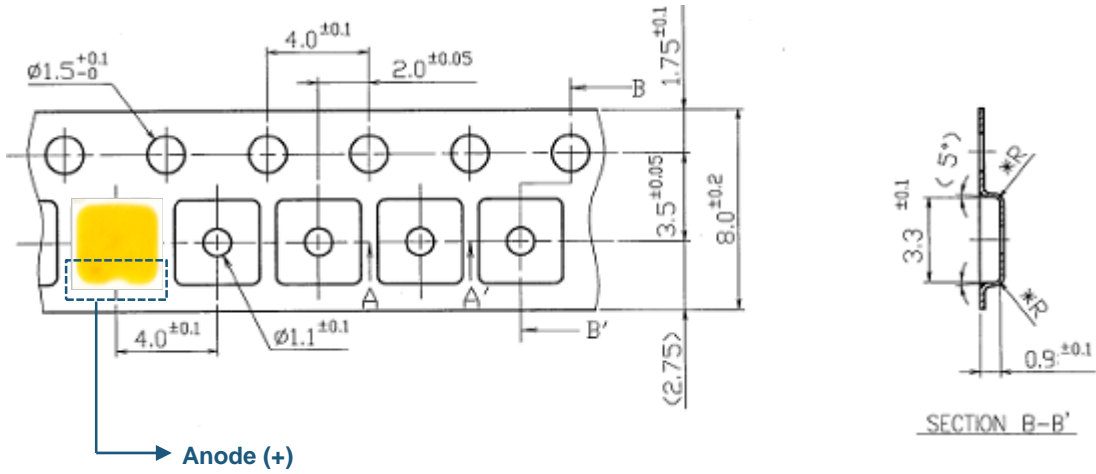

**IPC/JEDEC J-STD-020**
**Table 7.**

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (T <sub>smax</sub> to T <sub>p</sub> )	3° C/second max.	3° C/second max.
Preheat - Temperature Min (T <sub>smin</sub> ) - Temperature Max (T <sub>smax</sub> ) - Time (T <sub>smin</sub> to T <sub>smax</sub> ) (t <sub>s</sub> )	100 °C 150 °C 60-120 seconds	150 °C 200 °C 60-180 seconds
Time maintained above: - Temperature (T <sub>L</sub> ) - Time (t <sub>L</sub> )	183 °C 60-150 seconds	217 °C 60-150 seconds
Peak Temperature (T <sub>p</sub> )	215°C	260°C
Time within 5°C of actual Peak Temperature (t <sub>p</sub> ) <sup>2</sup>	10-30 seconds	20-40 seconds
Ramp-down Rate	6 °C/second max.	6 °C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

### Caution

- (1) Reflow soldering is recommended not to be done more than two times. In the case of more than 24 hours passed soldering after first, LEDs will be damaged.
- (2) Repairs should not be done after the LEDs have been soldered. When repair is unavoidable, suitable tools must be used.
- (3) Die slug is to be soldered.
- (4) When soldering, do not put stress on the LEDs during heating.
- (5) After soldering, do not warp the circuit board.

## Emitter Tape & Reel Packing

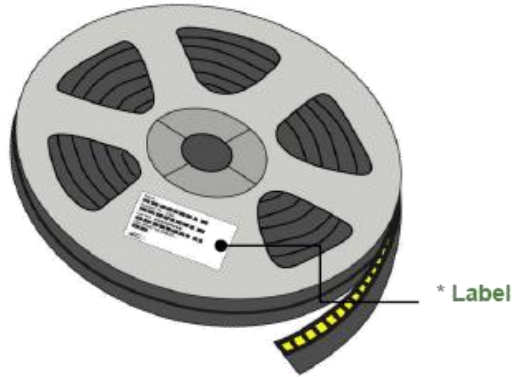


( Tolerance:  $\pm 0.2$ , Unit: mm )

- (1) Quantity : 4,500pcs/Reel
- (2) Cumulative Tolerance : Cumulative Tolerance/10 pitches to be  $\pm 0.2$ mm
- (3) Adhesion Strength of Cover Tape  
Adhesion strength to be 0.1-0.7N when the cover tape is turned off from the carrier tape at the angle of  $10^\circ$  to the carrier tape.
- (4) Package : P/N, Manufacturing data Code No. and Quantity to be indicated on a damp proof Package.

## Emitter Tape & Reel Packing

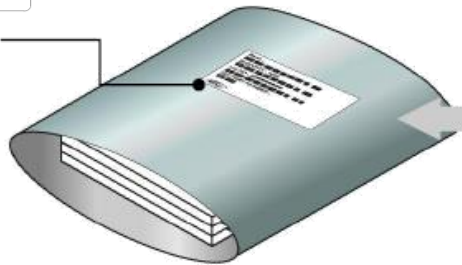
### Reel



### Aluminum Bag



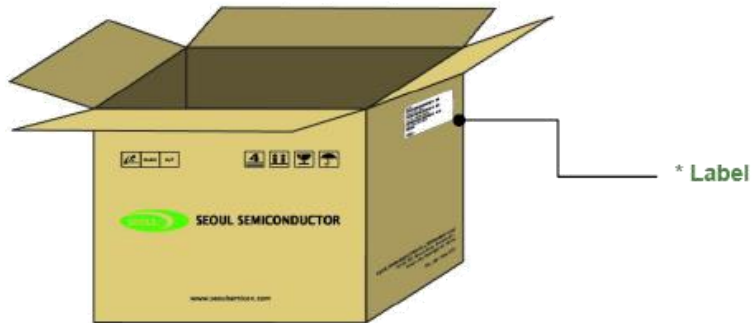
\* Label



Humidity Indicator

Desiccant

### Outer Box



\* Label

## Product Nomenclature

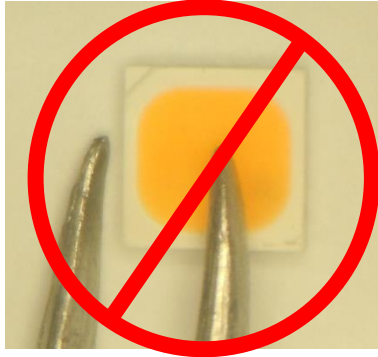
**Table 8. Part Numbering System**

Part Number Code	Description	Part Number	Value
X <sub>1</sub>	Company	S	Seoul Semiconductor
X <sub>2</sub>	Level of Integration	1	Discrete LED
X <sub>3</sub> X <sub>4</sub>	Technology	W0	General White
X <sub>5</sub> X <sub>6</sub> X <sub>7</sub> X <sub>8</sub>	Dimension	3030	
X <sub>9</sub> X <sub>10</sub>	CCT	XX	
X <sub>11</sub> X <sub>12</sub>	CRI	80	
X <sub>13</sub> X <sub>14</sub>	Vf	03	
X <sub>15</sub> X <sub>16</sub> X <sub>17</sub>	Characteristic code Flux Rank	000	
X <sub>18</sub> X <sub>19</sub> X <sub>20</sub>	Characteristic code Vf Rank	000	
X <sub>21</sub> X <sub>22</sub>	Characteristic code Color Step	00	
X <sub>23</sub> X <sub>24</sub>	Type	0P	
X <sub>25</sub> X <sub>26</sub> X <sub>27</sub>	Internal code	006	

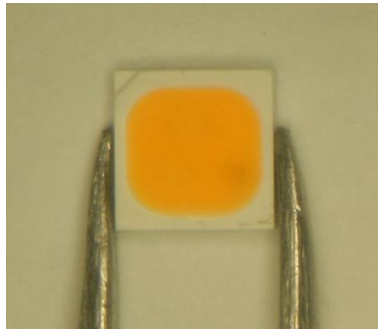


## Handling of Silicone Resin for LEDs

(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.



(2) In general, LEDs should only be handled from the side. By the way, this also applies to LEDs without a silicone sealant, since the surface can also become scratched.



(3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is larger than the LED's reflector area.

(4) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust.

As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of components.

(5) SSC suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin.

Ultrasonic cleaning is not recommended. Ultrasonic cleaning may cause damage to the LED.

(6) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this product with acid or sulfur material in sealed space.

## Precaution for Use

(1) Storage

To avoid the moisture penetration, we recommend store in a dry box with a desiccant. The recommended storage temperature range is 5°C to 30°C and a maximum humidity of RH50%.

(2) Use Precaution after Opening the Packaging

Use SMT techniques properly when you solder the LED as separation of the lens may affect the light output efficiency.

Pay attention to the following:

a. Recommend conditions after opening the package

- Sealing / Temperature : 5 ~ 40°C Humidity : less than RH30%

b. If the package has been opened more than 4 week(MSL\_2a) or the color of the desiccant changes, components should be dried for 10-12hr at 60±5°C

(3) Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.

(4) Do not rapidly cool device after soldering.

(5) Components should not be mounted on warped (non coplanar) portion of PCB.

(6) Radioactive exposure is not considered for the products listed here in.

(7) Gallium arsenide is used in some of the products listed in this publication. These products are dangerous if they are burned or shredded in the process of disposal. It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.

(8) This device should not be used in any type of fluid such as water, oil, organic solvent and etc. When washing is required, IPA (Isopropyl Alcohol) should be used.

(9) When the LEDs are in operation the maximum current should be decided after measuring the package temperature.

(10) LEDs must be stored properly to maintain the device. If the LEDs are stored for 3 months or more after being shipped from Seoul Semiconductor. A sealed container with a nitrogen atmosphere should be used for storage.

(11) The appearance and specifications of the product may be modified for improvement without notice.

(12) Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.

## Precaution for Use

(13) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures can penetrate silicone encapsulants of LEDs and discolor when exposed to heat and photonic energy. The result can be a significant loss of light output from the fixture. Knowledge of the properties of the materials selected to be used in the construction of fixtures can help prevent these issues.

(14) The slug is electrically isolated.

(15) Attaching LEDs, do not use adhesives that outgas organic vapor.

(16) The driving circuit must be designed to allow forward voltage only when it is ON or OFF. If the reverse voltage is applied to LED, migration can be generated resulting in LED damage.

(17) LEDs are sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS). Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.

### a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to LEDs may cause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event. One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

Environmental controls:

- Humidity control (ESD gets worse in a dry environment)

## Precaution for Use

### b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device. The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package  
(If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)
- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- Damaged may be noticed to the bond wires (appearing similar to a blown fuse)
- Damage to the bond pads located on the emission surface of the LED package  
(shadowing can be noticed around the bond pads while viewing through a microscope)
- Anomalies noticed in the encapsulation and phosphor around the bond wires.
- This damage usually appears due to the thermal stress produced during the EOS event.

### c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:

- A surge protection circuit
- An appropriately rated over voltage protection device
- A current limiting device



## Company Information

### Published by

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### Company Information

Seoul Semiconductor ([www.SeoulSemicon.com](http://www.SeoulSemicon.com)) manufactures and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

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